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## UltraCMOS® SPDT RF Switch, $10 \mathrm{MHz}-40 \mathrm{GHz}$

## Features

- Wideband support up to 40 GHz
- High port to port isolation
- 48 dB @ 26.5 GHz
- 39 dB @ 35 GHz
- 33 dB @ 40 GHz
- Excellent linearity performance
- P1dB of $31.5 \mathrm{dBm} @ 26.5 \mathrm{GHz}$
- P1dB of $28.0 \mathrm{dBm} @ 35 \mathrm{GHz}$
- IIP3 of 50 dBm @ 13.5 GHz
- Fast RF $\mathrm{T}_{\text {rise }} / T_{\text {fall }}$ time of 55 ns
- Low insertion loss
- 1.8 dB @ 26.5 GHz
- $3.1 \mathrm{~dB} @ 35 \mathrm{GHz}$
- Flip-chip die


## Applications

- Test and measurement
- Microwave backhaul
- Radar
- Military communications

Figure 1•PE42524 Functional Diagram


## Product Description

The PE42524 is a HaRPTM technology-enhanced reflective SPDT RF switch die that supports a wide frequency range from 10 MHz to 40 GHz . This wideband flip-chip switch delivers high isolation performance, excellent linearity and low insertion loss, making this device ideal for test and measurement (T\&M), microwave backhaul, radar and military communications (mil-comm) applications. At 30 GHz , the PE42524 exhibits 17 dB active port return loss, 47 dB isolation and 2.2 dB insertion loss. No blocking capacitors are required if DC voltage is not present on the RF ports.
The PE42524 is manufactured on Peregrine's UltraCMOS ${ }^{\circledR}$ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate.

Peregrine's HaRP technology enhancements deliver high linearity and excellent harmonics performance. It is an innovative feature of the UltraCMOS process, offering the performance of GaAs with the economy and integration of conventional CMOS.

## Absolute Maximum Ratings

Exceeding absolute maximum ratings listed in Table 1 may cause permanent damage. Operation should be restricted to the limits in Table 2. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

## ESD Precautions

When handling this UltraCMOS device, observe the same precautions as with any other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in Table 1.

## Latch-up Immunity

Unlike conventional CMOS devices, UltraCMOS devices are immune to latch-up.
Table 1•Absolute Maximum Ratings for PE42524

| Parameter/Condition | Min | Max | Unit |
| :--- | :---: | :---: | :---: |
| Control voltage (V1, V2) | -3.5 | 3.5 | V |
| RF input power (RFC-RFX, 50ת) |  | Fig. 2 | dBm |
| Storage temperature range | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| ESD voltage HBM, all pins ${ }^{(*)}$ |  | 2000 | V |

Note: * Human body model (MIL-STD883 Method 3015).

## Recommended Operating Conditions

Table 2 lists the recommended operating conditions for PE42524. Devices should not be operated outside the recommended operating conditions listed below.

Table 2•Recommended Operating Condition for PE42524

| Parameter | Min | Tур | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Control high (V1, V2) | 3.1 | 3.3 | 3.5 | V |
| Control low (V1, V2) | -3.5 | -3.3 | -3.1 | V |
| Control current |  | 2 |  | nA |
| RF input power, CW (RFC-RFX) ${ }^{(1)}$ |  |  | Fig. 2 | dBm |
| RF input power, pulsed (RFC-RFX) ${ }^{(2)}$ |  |  | Fig. 2 | dBm |
| Operating temperature range | -40 | +25 | +85 | ${ }^{\circ} \mathrm{C}$ |
| Notes: <br> 1) $100 \%$ duty cycle, all bands, $50 \Omega$. <br> 2) Pulsed, $5 \%$ duty cycle of $4620 \mu$ s period, $50 \Omega$. |  |  |  |  |

## Electrical Specifications

Table 3 provides the PE42524 key electrical specifications @ $25^{\circ} \mathrm{C}, \mathrm{V} 1=+3.3 \mathrm{~V}$, $\mathrm{V} 2=-3.3 \mathrm{~V}$ or $\mathrm{V} 1=-3.3 \mathrm{~V}$, V 2 $=+3.3 \mathrm{~V}\left(\mathrm{Z}_{\mathrm{S}}=\mathrm{Z}_{\mathrm{L}}=50 \Omega\right)$, unless otherwise specified.

Table 3•PE42524 Electrical Specifications

| Parameter | Path | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Operation frequency |  |  | $\begin{gathered} 10 \\ \mathrm{MHz} \end{gathered}$ |  | $\begin{gathered} 40 \\ \mathrm{GHz} \end{gathered}$ | As shown |
| Insertion loss | RFC-RFX | $\begin{aligned} & 10 \mathrm{MHz} \\ & 10 \mathrm{MHz}-7.5 \mathrm{GHz} \\ & 7.5-10 \mathrm{GHz} \\ & 10-13.5 \mathrm{GHz} \\ & 13.5-18 \mathrm{GHz} \\ & 18-20 \mathrm{GHz} \\ & 20-26.5 \mathrm{GHz} \\ & 26.5-30 \mathrm{GHz} \\ & 30-35 \mathrm{GHz} \\ & 35-40 \mathrm{GHz} \end{aligned}$ |  | $\begin{aligned} & 0.6 \\ & 1.0 \\ & 1.1 \\ & 1.3 \\ & 1.4 \\ & 1.4 \\ & 1.8 \\ & 2.2 \\ & 3.1 \\ & 5.5 \end{aligned}$ | $\begin{gathered} 0.85 \\ 1.30 \\ 1.50 \\ 1.65 \\ 1.75 \\ 1.75 \\ 2.20 \\ 2.70 \\ 4.10 \\ - \end{gathered}$ | dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB |

Table 3 • PE42524 Electrical Specifications

| Parameter | Path | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Isolation | All paths | $\begin{aligned} & 10 \mathrm{MHz} \\ & 10 \mathrm{MHz}-7.5 \mathrm{GHz} \\ & 7.5-10 \mathrm{GHz} \\ & 10-13.5 \mathrm{GHz} \\ & 13.5-18 \mathrm{GHz} \\ & 18-20 \mathrm{GHz} \\ & 20-26.5 \mathrm{GHz} \\ & 26.5-30 \mathrm{GHz} \\ & 30-35 \mathrm{GHz} \\ & 35-40 \mathrm{GHz} \end{aligned}$ | $\begin{aligned} & 74 \\ & 60 \\ & 58 \\ & 51 \\ & 50 \\ & 49 \\ & 44 \\ & 43 \\ & 35 \\ & 28 \end{aligned}$ | $\begin{aligned} & 84 \\ & 64 \\ & 65 \\ & 58 \\ & 53 \\ & 52 \\ & 48 \\ & 47 \\ & 39 \\ & 33 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB |
| Return loss (active port) | RFC-RFX | $\begin{aligned} & 10 \mathrm{MHz} \\ & 10 \mathrm{MHz}-7.5 \mathrm{GHz} \\ & 7.5-10 \mathrm{GHz} \\ & 10-13.5 \mathrm{GHz} \\ & 13.5-18 \mathrm{GHz} \\ & 18-20 \mathrm{GHz} \\ & 20-26.5 \mathrm{GHz} \\ & 26.5-30 \mathrm{GHz} \\ & 30-35 \mathrm{GHz} \\ & 35-40 \mathrm{GHz} \end{aligned}$ |  | $\begin{gathered} 25 \\ 16 \\ 15 \\ 17 \\ 21 \\ 21 \\ 18 \\ 17 \\ 14 \\ 6 \end{gathered}$ |  | dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB |
| Return loss (RFC port) | RFC-RFX | $\begin{aligned} & 10 \mathrm{MHz} \\ & 10 \mathrm{MHZ}-7.5 \mathrm{GHz} \\ & 7.5-10 \mathrm{GHz} \\ & 10-13.5 \mathrm{GHz} \\ & 13.5-18 \mathrm{GHz} \\ & 18-20 \mathrm{GHz} \\ & 20-26.5 \mathrm{GHz} \\ & 26.5-30 \mathrm{GHz} \\ & 30-35 \mathrm{GHz} \\ & 35-40 \mathrm{GHz} \end{aligned}$ |  | $\begin{gathered} 25 \\ 18 \\ 19 \\ 26 \\ 29 \\ 23 \\ 31 \\ 30 \\ 16 \\ 7 \end{gathered}$ |  | dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB <br> dB |
| 2nd harmonic, 2fo rejection | RFC-RFX | +25 dBm output power, 1 GHz <br> +25 dBm output power, 6.5 GHz <br> +25 dBm output power, 15 GHz |  | $\begin{array}{r} 88 \\ 84 \\ >89^{(1)} \end{array}$ |  | dBc <br> dBc <br> dBc |
| Input 1dB compression point ${ }^{(2)}$ |  | $10 \mathrm{MHz}-40 \mathrm{GHz}$ |  | Fig. 2 |  | dBm |
| Input IP3 |  | $\begin{aligned} & 10-100 \mathrm{MHz} \\ & 1-2 \mathrm{GHz} \\ & 6-10 \mathrm{GHz} \\ & 10-13.5 \mathrm{GHz} \end{aligned}$ |  | $\begin{aligned} & 48 \\ & 50 \\ & 52 \\ & 50 \end{aligned}$ |  | dBm <br> dBm <br> dBm <br> dBm |
| Video feedthrough ${ }^{(3)}$ |  | DC measurement |  | 3.5 |  | $m V_{P P}$ |
| RF $\mathrm{T}_{\text {rise }} / \mathrm{T}_{\text {fall }}$ |  | 10\%/90\% RF |  | 55 |  | ns |
| Settling time |  | $50 \%$ CTRL to 0.05 dB final value |  | 0.84 | 1.13 | $\mu \mathrm{s}$ |

Table 3•PE42524 Electrical Specifications

| Parameter | Path | Condition | Min | IVp | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Switching time |  | $50 \%$ CTRL to $90 \%$ or $10 \%$ RF |  | 225 | 304 | ns |
| Notes: <br> 1) Test system limited. <br> 2) The input 1 dB compression point is a linearity figure of merit. Refer to Table 2 for the RF input power ( $50 \Omega$ ). <br> 3) Measured with a 3.5 ns rise time, $-3.3 /+3.3 \mathrm{~V}$ pulse and 500 MHz bandwidth. |  |  |  |  |  |  |

## Control Logic

Table 4 provides the control logic truth table for the PE42524. States 2 and 3 are used in normal switching operations.

Table 4 • Truth Table for PE42524

| V 1 | V 2 | RF1 | RF2 | State |
| :---: | :---: | :---: | :---: | :---: |
| -3.3 V | -3.3 V | OFF | OFF | 1 |
| -3.3 V | +3.3 V | OFF | ON | 2 |
| +3.3 V | -3.3 V | ON | OFF | 3 |
| +3.3 V | +3.3 V | ON | ON | 4 |

Figure 2•Power De-rating Curve (10 MHz-40 GHz) @ $25^{\circ} \mathrm{C}$ and $85^{\circ} \mathrm{C}$ Ambient (50 )


## Typical Performance Data

Figure 3-Figure 12 show the typical performance data @ $25^{\circ} \mathrm{C}, \mathrm{V} 1=+3.3 \mathrm{~V}, \mathrm{~V} 2=-3.3 \mathrm{~V}$, unless otherwise specified.

Figure $3 \cdot$ Insertion Loss vs Temperature (RFC-RFX)


Figure $4 \cdot$ Insertion Loss vs V1/V2 (RFC-RFX)


Figure 5•RFC Port Return Loss vs Temperature


Figure 6-RFC Port Return Loss vs V1/V2


Figure 7 • Active Port Return Loss vs Temperature


Figure 8 • Active Port Return Loss vs V1/V2


Figure 9 - Isolation vs Temperature (RFX-RFX)


Figure $10 \cdot$ Isolation vs V1/V2 (RFX-RFX)


Figure 11•Isolation vs Temperature (RFC-RFX)


Figure $12 \cdot$ Isolation vs V1/V2 (RFC-RFX)


## Recommended Evaluation Setup

The PE42524 s-parameter data and input 1 dB compression point from $22-40 \mathrm{GHz}$ (Table 3 and Figure 3Figure 12) were taken using grounded co-planar waveguide (CPWG) on the alumina substrate (shown in Figure 13) and RF probes.
The PE42524 2nd harmonic, 2fo rejection, input 1 dB compression point below 18 GHz , input IP3 measurements, settling time and switching time (Table 3) were taken on a PCB using 2.92 mm connectors.
Bypass capacitors are not required.
Figure 13 • Alumina Substrate Board for PE42524


## Pin Configuration

This section provides pin information for the PE42524. Figure 14 shows the pin configuration of this device. Table 5 provides a description for each pin.

Figure 14• Pin Configuration (Bumps Up) for PE42524


Table 5•Pin Descriptions for PE42524

| Pin No. | Pin <br> Name |  |
| :---: | :---: | :--- |
| $1,2,5,6$, <br> $8-10,12-$ <br> $14,16-19$ | GND | Ground |
| 7 | RF1 | RF port 1 |
| 11 | RFC | RF common port |
| 15 | RF2 | RF port 2 |
| 3 | V1 | Control input 1 |
| 4 | V2 | Control input 2 |

## Die Mechanical Specifications

This section provides the die mechanical specifications for the PE42524.
Table 6-Mechanical Specifications for PE42524

| Parameter | Min | Typ | Max | Unit |  |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Die size, singulated (x, y) | $2466 \times 2120$ | $2486 \times 2140$ | $2516 \times 2170$ | $\mu \mathrm{~m}$ | Including excess sapphire, <br> max. tolerance $=-20 /+30 \mu \mathrm{~m}$ |
| Wafer thickness | 180 | 200 | 220 | $\mu \mathrm{~m}$ |  |
| Wafer size |  | 150 |  | mm |  |
| Bump pitch | 500 |  |  | $\mu \mathrm{~m}$ |  |
| Bump height | 72.5 | 85 | 97.75 | $\mu \mathrm{~m}$ |  |
| Bump diameter |  | 110 |  | $\mu \mathrm{~m}$ |  |
| UBM diameter | 85 | 90 | 95 | $\mu \mathrm{~m}$ |  |

Table 7•Pin Coordinates for PE42524 ${ }^{(*)}$

| Pin \# | Pin Name | Pin Center ( $\mu \mathrm{m}$ ) |  |
| :---: | :---: | :---: | :---: |
|  |  | X | Y |
| 1 | GND | 1128.5 | -958.5 |
| 2 | GND | 731.5 | -646.5 |
| 3 | V1 | 253.5 | -958.5 |
| 4 | V2 | -253.5 | -958.5 |
| 5 | GND | -1128.5 | -958.5 |
| 6 | GND | -731.5 | -646.5 |
| 7 | RF1 | -785.5 | -121.5 |
| 8 | GND | -931.5 | 363.5 |
| 9 | GND | -1091.5 | 913.5 |
| 10 | GND | -503.5 | 753.5 |
| 11 | RFC | 0 | 629 |
| 12 | GND | 503.5 | 753.5 |
| 13 | GND | 1091.5 | 913.5 |
| 14 | GND | 931.5 | 363.5 |
| 15 | RF2 | 785.5 | -121.5 |
| 16 | GND | 253.5 | 183.5 |
| 17 | GND | 253.5 | -326.5 |
| 18 | GND | -253.5 | 183.5 |
| 19 | GND | -253.5 | -326.5 |

Note: * All pin locations originate from the die center and refer to the center of the pin.

Figure 15 • Pin Layout for PE42524 ${ }^{(1)(2)}$


## Notes:

1) Drawings are not drawn to scale.
2) Singulated die size shown, bump side up.

## Tape and Reel Specification

This section provides the tape and reel specifications for the PE42524.
Figure 16 • Tape and Reel Specifications for PE42524


## Ordering Information

Table 8 lists the available ordering code for the PE42524 as well as shipping method.

## Table 8•Order Code for PE42524

| Order Code | Description | Packaging | Shipping Method |
| :---: | :---: | :---: | :---: |
| PE42524A-X | PE42524 SPDT RF switch | Die on tape and reel | 500 die $/$ T\&R |

## Document Categories

## Advance Information

The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

## Preliminary Specification

The datasheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

## Product Specification

The datasheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a CNF (Customer Notification Form).

## Product Brief

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This product is in production but is not recommended for new designs.

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This product is currently going through the EOL process. It has a specific last-time buy date.

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